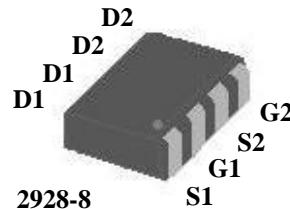


- ▼ Simple Drive Requirement
- ▼ Low Gate Charge
- ▼ Fast Switching Performance
- ▼ RoHS Compliant & Halogen-Free

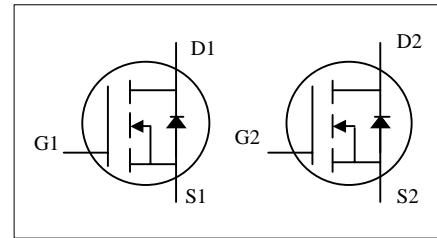


$BV_{DSS}$	30V
$R_{DS(ON)}$	20mΩ
$I_D^3$	6.5A

## Description

XP3A020 series are innovated design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

The 2928-8 J-lead package provides good on-resistance performance and space saving like TSOP-6.



## Absolute Maximum Ratings@ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	30	V
$V_{GS}$	Gate-Source Voltage	+20	V
$I_D @ T_A=25^\circ\text{C}$	Drain Current, $V_{GS} @ 10\text{V}^3$	6.5	A
$I_D @ T_A=70^\circ\text{C}$	Drain Current, $V_{GS} @ 10\text{V}^3$	5.2	A
$I_{DM}$	Pulsed Drain Current <sup>1</sup>	20	A
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation	1.38	W
$E_{AS}$	Single Pulse Avalanche Energy <sup>4</sup>	7.2	mJ
$T_{STG}$	Storage Temperature Range	-55 to 150	°C
$T_J$	Operating Junction Temperature Range	-55 to 150	°C

## Thermal Data

Symbol	Parameter	Value	Unit
$R_{thj-a}$	Maximum Thermal Resistance, Junction-ambient <sup>3</sup>	90	°C/W

### Electrical Characteristics@ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}$ , $I_{\text{D}}=250\mu\text{A}$	30	-	-	V
$R_{\text{DS}(\text{ON})}$	Static Drain-Source On-Resistance <sup>2</sup>	$V_{\text{GS}}=10\text{V}$ , $I_{\text{D}}=6\text{A}$	-	-	20	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}$ , $I_{\text{D}}=4\text{A}$	-	-	35	$\text{m}\Omega$
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}$ , $I_{\text{D}}=1\text{mA}$	1.4	-	2.5	V
$g_{\text{fs}}$	Forward Transconductance	$V_{\text{DS}}=5\text{V}$ , $I_{\text{D}}=6\text{A}$	-	22	-	S
$I_{\text{DSS}}$	Drain-Source Leakage Current	$V_{\text{DS}}=24\text{V}$ , $V_{\text{GS}}=0\text{V}$	-	-	10	$\text{uA}$
$I_{\text{GSS}}$	Gate-Source Leakage	$V_{\text{GS}}=\pm 20\text{V}$ , $V_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	nA
$Q_{\text{g}}$	Total Gate Charge	$I_{\text{D}}=4\text{A}$	-	5	8	nC
$Q_{\text{gs}}$	Gate-Source Charge	$V_{\text{DS}}=15\text{V}$	-	1.8	-	nC
$Q_{\text{gd}}$	Gate-Drain ("Miller") Charge		-	1.8	-	nC
$t_{\text{d}(\text{on})}$	Turn-on Delay Time	$V_{\text{DS}}=15\text{V}$	-	7	-	ns
$t_{\text{r}}$	Rise Time	$I_{\text{D}}=1\text{A}$	-	7	-	ns
$t_{\text{d}(\text{off})}$	Turn-off Delay Time	$R_{\text{G}}=6\Omega$	-	16	-	ns
$t_{\text{f}}$	Fall Time	$V_{\text{GS}}=10\text{V}$	-	4	-	ns
$C_{\text{iss}}$	Input Capacitance	$V_{\text{GS}}=0\text{V}$	-	550	880	pF
$C_{\text{oss}}$	Output Capacitance	$V_{\text{DS}}=15\text{V}$	-	90	-	pF
$C_{\text{rss}}$	Reverse Transfer Capacitance		-	60	-	pF
$R_{\text{g}}$	Gate Resistance	$f=1.0\text{MHz}$	-	2.5	5	$\Omega$

### Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_{\text{SD}}$	Forward On Voltage <sup>2</sup>	$I_{\text{S}}=1.2\text{A}$ , $V_{\text{GS}}=0\text{V}$	-	-	1.2	V
$t_{\text{rr}}$	Reverse Recovery Time	$I_{\text{S}}=6\text{A}$ , $V_{\text{GS}}=0\text{V}$	-	8	-	ns
$Q_{\text{rr}}$	Reverse Recovery Charge	$dI/dt=100\text{A}/\mu\text{s}$	-	2	-	nC

### Notes:

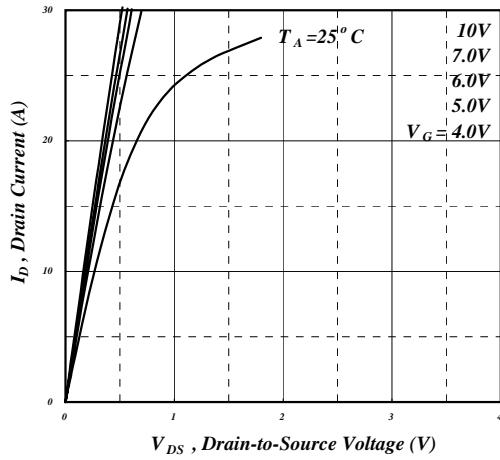
- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in<sup>2</sup> copper pad of FR4 board,  $t \leq 10\text{sec}$  ;  $210^\circ\text{C}/\text{W}$  when mounted on Min. copper pad.
- 4.Starting  $T_j=25^\circ\text{C}$  ,  $V_{\text{DD}}=30\text{V}$  ,  $L=0.1\text{mH}$  ,  $R_{\text{G}}=25\Omega$

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

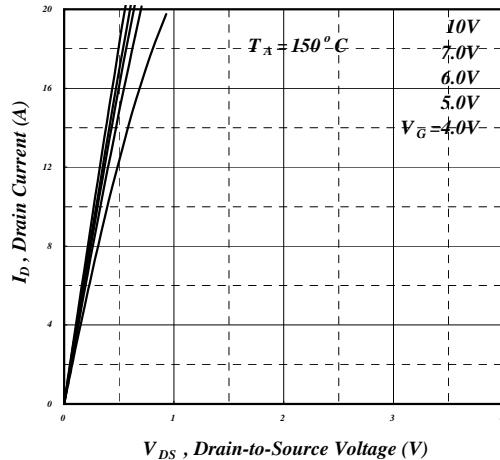
USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

XSEMI DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

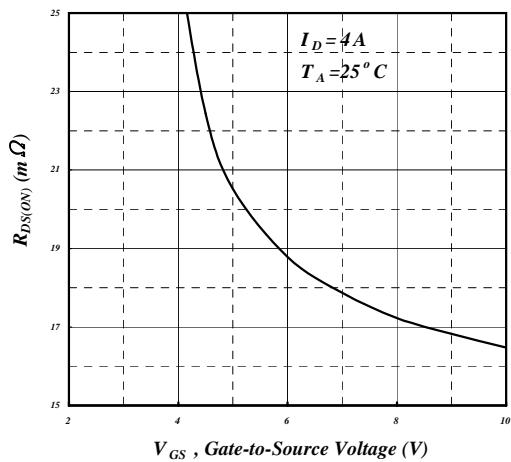
XSEMI RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.



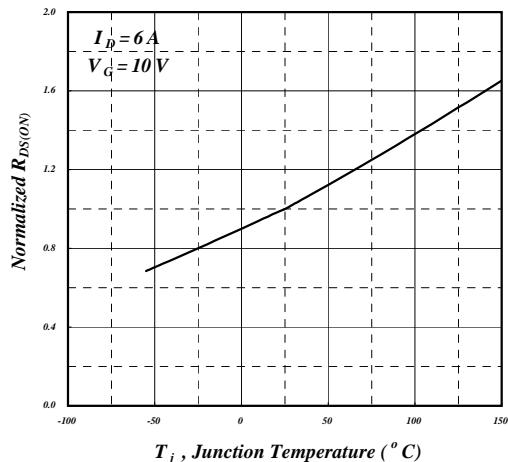
**Fig 1. Typical Output Characteristics**



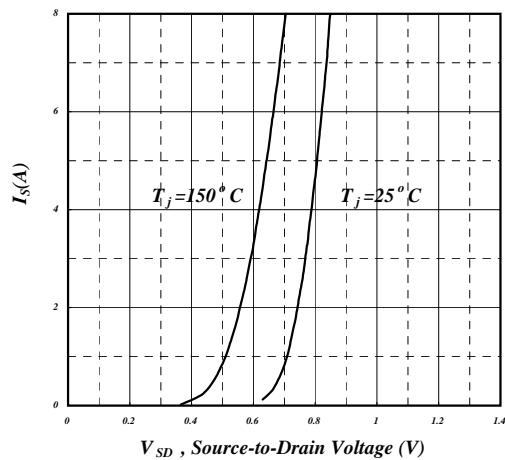
**Fig 2. Typical Output Characteristics**



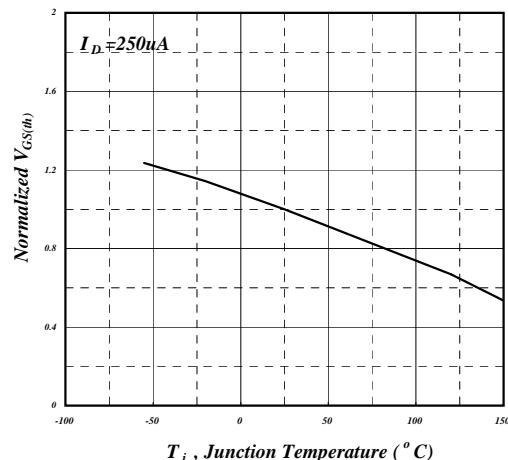
**Fig 3. On-Resistance v.s. Gate Voltage**



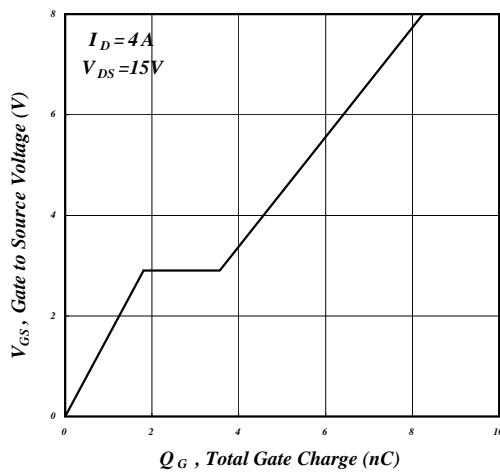
**Fig 4. Normalized On-Resistance v.s. Junction Temperature**



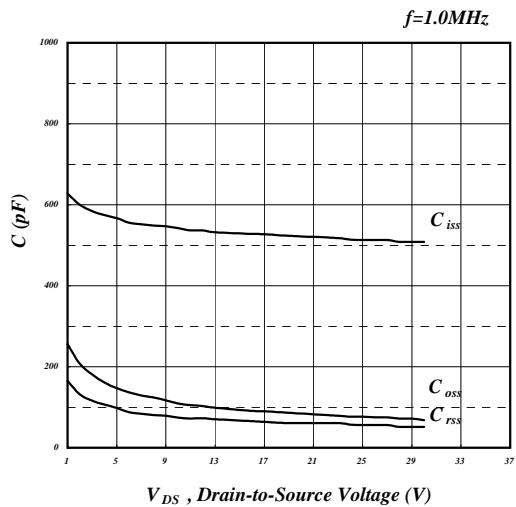
**Fig 5. Forward Characteristic of Reverse Diode**



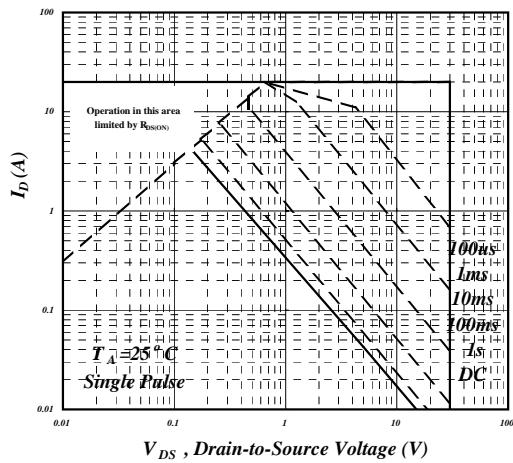
**Fig 6. Gate Threshold Voltage v.s. Junction Temperature**



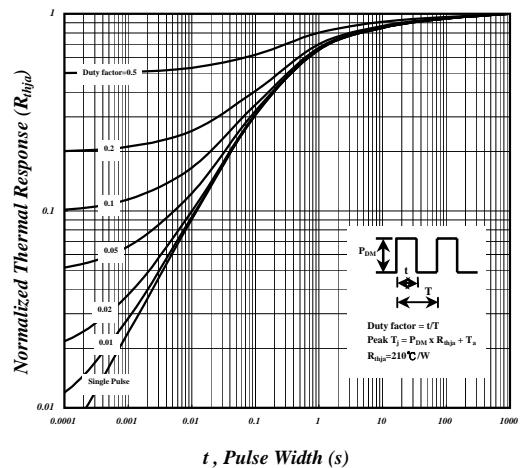
**Fig 7. Gate Charge Characteristics**



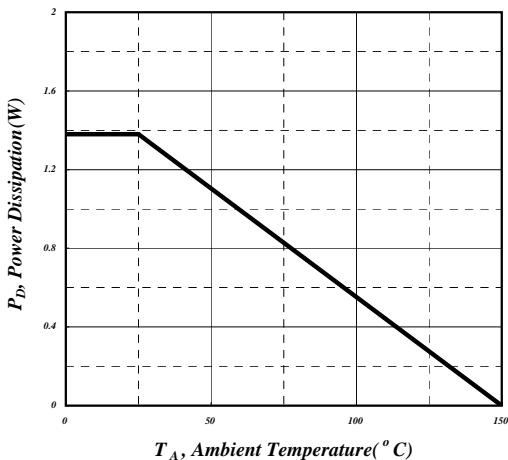
**Fig 8. Typical Capacitance Characteristics**



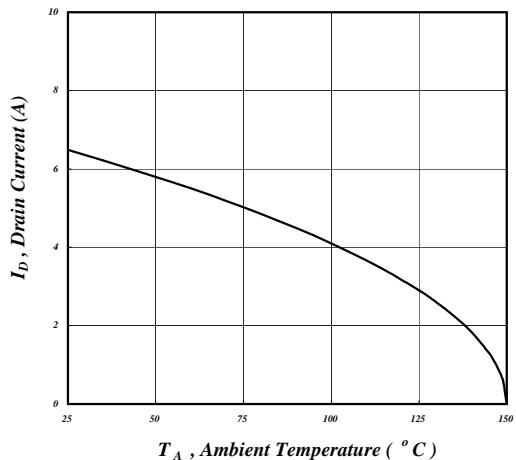
**Fig 9. Maximum Safe Operating Area**



**Fig 10. Effective Transient Thermal Impedance**



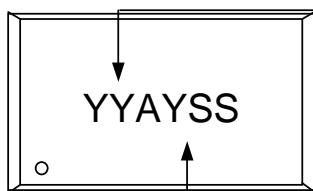
**Fig 11. Total Power Dissipation**



**Fig 12. Drain Current v.s. Ambient Temperature**

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## **MARKING INFORMATION**



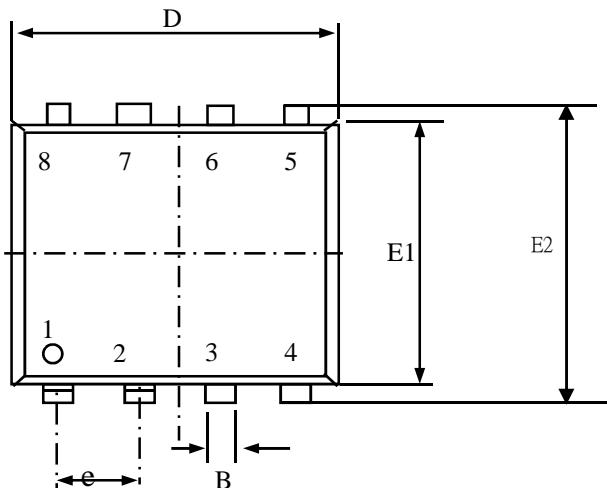
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Date Code (YSS)

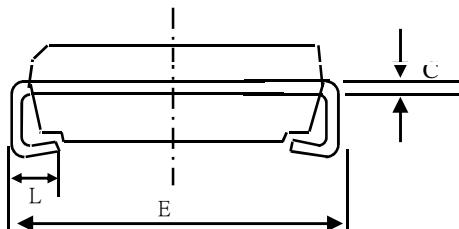
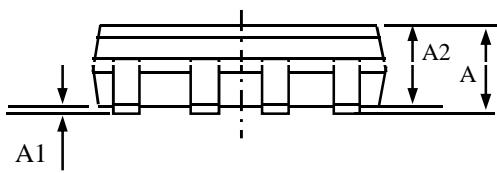
Y : Last Digit Of The Year

SS : Sequence

## Package Outline : 2928-8



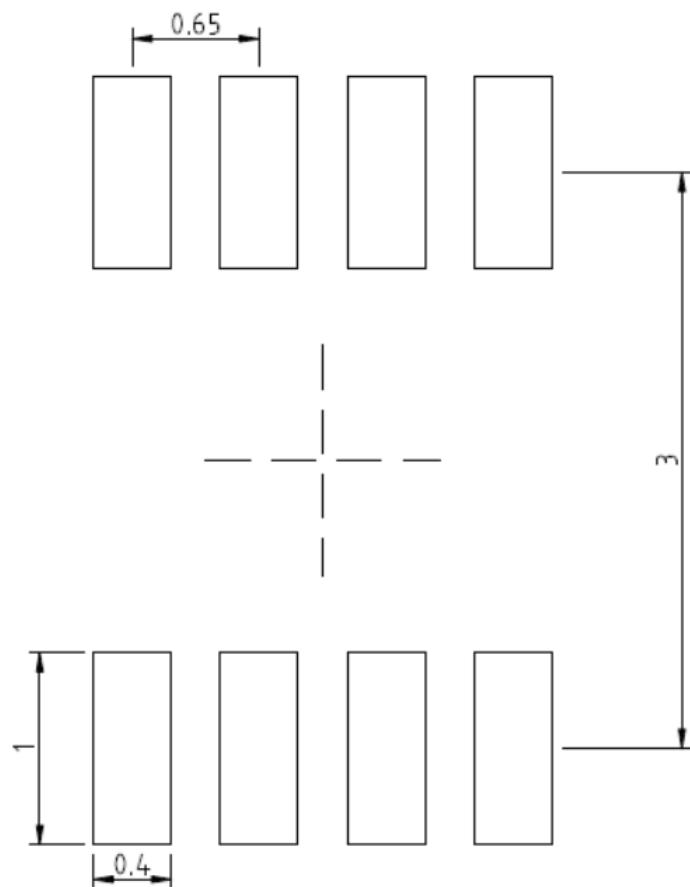
SYMBOLS	Millimeters		
	MIN	NOM	MAX
E	2.50	----	3.00
E1	2.30	2.40	2.50
E2	2.65	2.85	3.05
L	0.30	0.45	0.60
A	0.93	---	1.10
A1	0.01	---	0.10
A2	0.92	---	1.00
D	2.95	3.05	3.10
B	0.25	0.32	0.40
C	0.10	0.15	0.20
e	0.65BSC		



- Note:
- All Dimensions Are in Millimeters.
  - Package Body Sizes Exclude Mold Flash, Protrusion or Gate Burrs.  
Mold Flash, Protrusion or Gate Burrs Shall Not Exceed 0.10mm Per Side.
  - Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
  - The Package Top May Be Smaller Than The Package Bottom.
  - Dimension "b" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08mm Total In Excess Of "b" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.

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**2928-8 FOOTPRINT :**



UNIT: mm